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# SZA-6044

5.1GHzto 5.9GHz ¼WATT POWER AMPLIFIER WITH ACTIVE BIAS

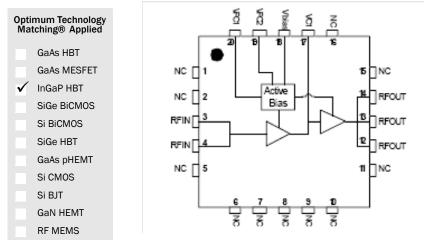


### Package: QFN, 4mmx4mm



### **Product Description**

RFMD's SZA-6044 is a high linearity Class A GaAs Heterojunction Bipolar Transistor (HBT) amplifier housed in a low-cost surface-mountable plastic package. These HBT amplifiers are fabricated using molecular beam epitaxial growth technology which produces reliable and consistent performance from wafer to wafer and lot to lot. This product is specifically designed as a driver or final stage amplifier for equipment in the 5.1GHzto5.9GHz band. It can run from a 3Vto5V supply. Load line optimization for target band is possible outside the package. Its high linearity makes it an ideal choice for multicarrier and digital applications.



#### **Features**

- Single 3V to 5V Operation
- High Linearity Class A OIP<sub>3</sub>=39dBm at 5V
- 802.11a 54 Mb/s P<sub>OUT</sub>=17 dBm at 3% EVM
- P<sub>1dB</sub> 24 dBm at 5 V, 21 dBm at 3.3 V
- Surface Mount Plastic Package
- Power Up/Down Control <1µs</p>

### **Applications**

- OFDM
- Multicarrier Applications
- 802.11a WLAN Driver Stage
- Fixed Wireless, UNII

Devementer		Specification	I	Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Frequency of Operation,	5100		5900	MHz		
Output Power at 1dB Compression		24.9		dBm	5.1GHz	
		24.6		dBm	5.5GHz	
	22.5	24.0	26.0	dBm	5.9GHz	
Small Signal Gain	17.0	18.5	20.0	dB	5.1GHz	
		17.3		dB	5.5GHz	
	14.9	16.4	17.9	dB	5.9GHz	
Worst Case Input Return Loss	8.0	11.0		dB	5.1GHzto5.9GHz	
Worst Case Output Return Loss	12.0	17.0		dB	5.1GHzto5.9GHz	
Output IP <sub>3</sub>	37.0	39.0		dBm	P <sub>OUT</sub> per tone=+8dBm@5.9GHz	
P <sub>OUT</sub>		17.0		dBm	802.11a 54Mb/s POUT@3% EVM@5.9GHz, I=165mA	
Noise Figure,		7.8	9.8	dB	5.9GHz	
Total Device Current	145.0	165.0	185.0	mA	I <sub>VBIAS</sub> +I <sub>CTOTAL</sub> =150mA, I <sub>VPC12</sub> =15mA	
Thermal Resistance		56		°C/W	junction - lead	

Test Conditions:  $Z_0 = 50 \Omega$ ,  $V_{CC} = 5V$ , I = 165 mA,  $T_{BP} = 30 \degree \text{C}$ 

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#### **Absolute Maximum Ratings**

0					
Parameter	Rating	Unit			
1st stage Collector Bias Current ( $I_{VC1}$ )	100	mA			
2nd Stage Collector Bias Current (I <sub>VC2</sub> )	190	mA			
Device Voltage (V <sub>D</sub> )	6.0	V			
Power Dissipation	1.5	W			
Operating Lead Temperature $(T_L)$	-40to+85	°C			
RF Input Power	20	dBm			
Junction Temp (T <sub>J</sub> )	+150	°C			
Storage Temperature Range	-40 to +150	°C			
ESD Rating - Human Body Model, Class 1B (HBM)	500	V			

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:  $I_D V_D < (T_J - T_L) / R_{TH},$  j-l

IDQ

Freq

٧S

#### Typical Performance with 2.45 GHz Application Circuit VCE



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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Comments

(MHz)	(v)	(V)	(mA)	(dBm)	(dBm)	(dB)	(dB)	(dB)	(dB)	
2.4	3.3	2.7	11.0	9.6	27.0	15.0	16.5	17.0	1.4	
2.45	3.3	2.7	11.0	9.9	27.0	14.8	18.0	18.0	1.5	Series Feedback
2.5	3.3	2.7	11.0	9.8	27.0	14.6	18.5	19.0	1.5	
Test Conditions: OIP3 Tone Spacing=1MHz, P <sub>OUT</sub> per tone=-5dBm. T <sub>L</sub> =25°C										

0IP3

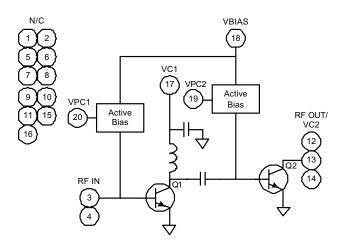
Gain

S11

S22

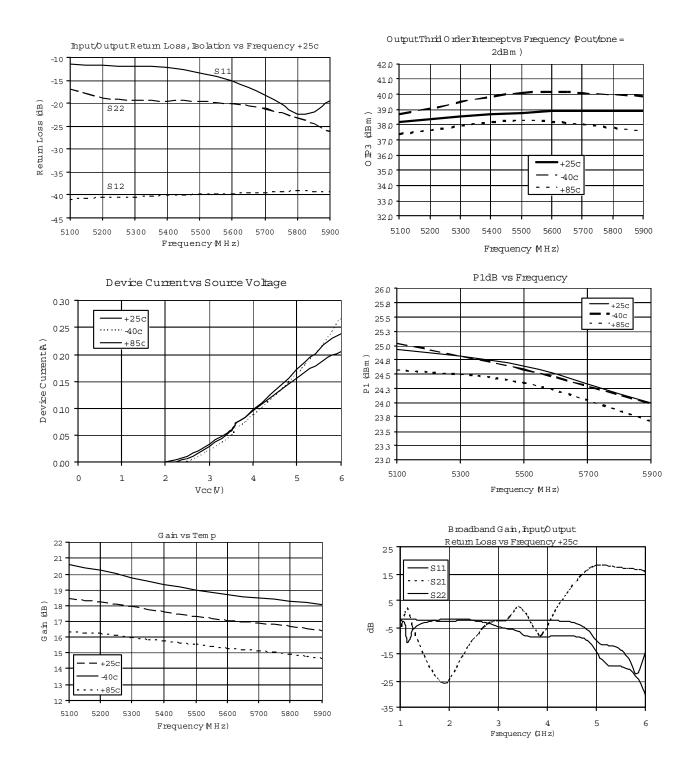
#### **Simplified Device Schematic**

P1dB





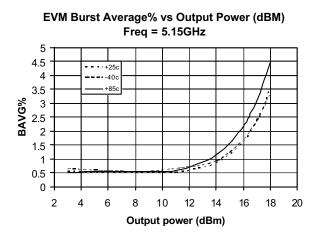
#### 5.1 - 5.9 GHz Evaluation Board Data (V $_{\rm B\,I\!A\,S}$ = 5.0V , $I_{\rm B\,I\!A\,S}$ = 165m A)



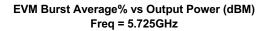
7628 Thorndike Road, Greensboro, NC 27409-9421 · For sales or technical support, contact RFMD at (+1) 336-678-5570 or sales-support@rfmd.com.

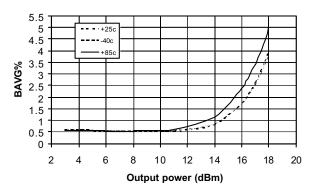


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### 802.11a 64QAM 54Mb/s Error Vector Magnitude Data (V<sub>BIAS</sub> = 5.0V, I<sub>BIAS</sub> = 165mA)





EVM Burst Average% vs Output Power (dBM) Freq = 5.875GHz

12

Output power (dBm)

14

16 18

EVM Burst Average% vs Output Power (dBM)

Freq = 5.35GHz

+250

-40c

+850

6 8 10

5

4

4.5

3.5

2.5

2

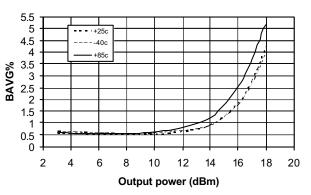
1.5

0.5

1

0 2 4

**BAVG%** 3



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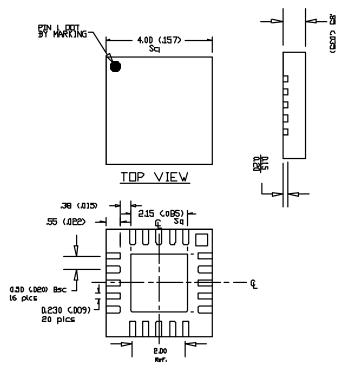
Pin	Function	Description			
1, 2,	N/C	Pins are not used. May be grounded, left open or connected to adjacent pin.			
5, 6,					
7, 8,					
9, 10,					
11,					
15,16					
19	VPC2	VPC2 is the bias control pin for the stage 2 active bias circuit. An external series resistor is required for proper setting of bias levels. Refer to the evaluation board schematic for resistor value.			
20	VPC1	PC1 VPC1 is the control pin for the stage 1 active bias circuits. An external series resistor is required for proper set-ting of bias levels. Refer to the evaluation board schematic for resistor value.			
18	VBIAS	VBIAS is the active bias circuit supply voltage. Can be operated from 3Vto5V.			
3,4	RFIN	RF input pin. This is DC grounded internal to the IC. Do not apply voltage to this pin. Both pins 3 and 4 must be used for proper operation.			
12, 13, 14	RFOUT/ VC2	RF output and second stage collector supply voltage pin. VC2 in the range of 3Vto5V voltage should be sup-plied to this pin through an external RF choke. Because DC biasing is present on this pin, a DC blocking capacitor should be used in most applications (see evaluation board schematic). The supply side of the bias network should be well bypassed. The output network and board layout specified in the app circuit is recommended for optimum performance. All pins 12-14 are required to be wired together at lead foot for proper operation.			
17	VC1	VC1 is the first stage collector supply voltage. Can be operated over the range of 3Vto5V.			
EPAD	Gnd	Exposed area on the bottom side of the package needs to be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the rec-ommended land pattern.			





## **Package Drawing**

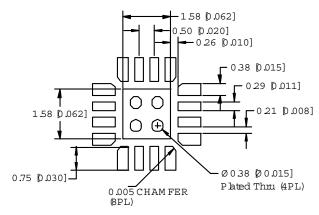
Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.



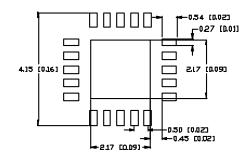
BOTTOM VIEW

### Land Pattern and PCB Soldermask

Recommended Land Pattern (dimensions in mm [in]):

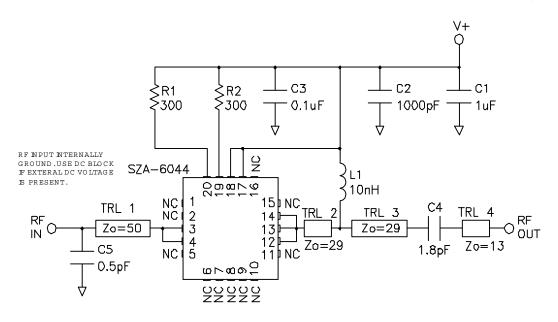


Recommended PCB Soldermask (SMBOC) for Land Pattern (dimensions in mm [in]):



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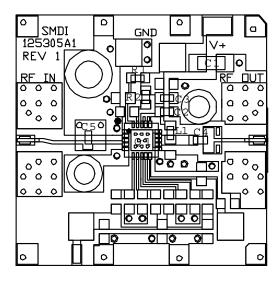




### 5.1GHz to 5.9GHz Evaluation Board Schematic For 5V Supply

### **Evaluation Board Layout and Bill of Materials**

DESG	DESCRIPTION				
Q1	SZA-6044				
R1,2	300 OHM, 0603				
C1	1uF CERAMIC CAP				
C2	1000pF CAP, 0603				
С3	0 1uF CAP, 0603				
C4	1.8pF CAP, 0603				
C5	0.5pF CAP, 0603				
L1	10nH INDUCTOR, 0603 Toko LL1608-FS10NJ				
TRL 1	Zo=50v,54.2 <sup>8</sup> @5.5GHz				
TRL 2	Zo=29v,22.3 <sup>8</sup> @5.5GHz				
TRL 3	Zo=29 <sup>v</sup> ,38.4 <sup>8</sup> @ 5.5GHz				
TRL 4	Zo=13 <sup>v</sup> ,16 <sup>8</sup> @ 5.5GHz				



Note: For 3.3V 140m A operation, lower V+ to 3.3V and change R1 and R2 to 50 ohm .

RF Perform ance at 3.3V, 140m A : Gain increases 0.5dB, IP3 drops ~ 3dB and P1dB drops ~3dB relative to 5V data. Return loss is essentially unchanged relative to 5V data. Contact factory form ore details.





## **Part Identification**

The part will be symbolized with an "SZA-6044" marking designator on the top surface of the package.

## **Ordering Information**

[	Part Number	Reel Size	Devices/Reel		
	SZA6044	13"	3000		
	SZA6044Z-EVB1	5.1GHz to 5.9GHz Frequency Range			